

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





PNP SILICON PLANAR EPITAXIAL SWITCHING TRANSISTORS

2N4402 / 2N4403



TO-92
Plastic Package
For Lead Free Parts, Device
Part # will be Prefixed with
"T"

General Purpose Switching And Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (T₂=25°C)

	a = /		
DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	40	V
Collector Base Voltage	V_{CBO}	40	V
Emitter Base Voltage	V_{EBO}	5.0	V
Collector Current Continuous	I _C	600	mA
Power Dissipation at T _a =25°C	P _D	625	mW
Derate Above 25°C		5.0	mW/°C
Power Dissipation at T _c =25°C	P_{D}	1.5	W
Derate Above 25°C		12	mW/ºC
Operating And Storage Junction Temperature Range	T_j , T_{stg}	-55 to +150	°C

THERMAL RESISTANCE

Junction to Case	R _{th (j-c)}	83.3	°C/W
Junction to Ambient in free air	R _{th (j-a)}	200	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	$I_C=1mA, I_B=0$	40		V
Collector Base Voltage	V_{CBO}	I _C =100μΑ. I _E =0	40		V
Emitter Base Voltage	V_{EBO}	$I_{E}=100\mu A, I_{C}=0$	5.0		V
Base Cut Off Current	I_{BEV}	V_{CE} =35V, V_{EB} =0.4V		100	nA
Collector Cut Off Current	I _{CEX}	V_{CE} =35V, V_{EB} =0.4V		100	nA
			2N4402	2N4403	
DC Current Gain	*h _{FE}	$I_C=0.1$ mA, $V_{CE}=1$ V	-	>30	
		$I_C=1mA$, $V_{CE}=1V$	>30	>60	
		$I_C=10$ mA, $V_{CE}=1$ V	>50	>100	
		$I_C=150$ mA, $V_{CE}=2$ V	50 - 150	100 - 300	
		$I_C=500$ mA, $V_{CE}=2$ V	>20	>20	

*Pulse Test: Pulse Width < 300ms, Duty Cycle < 2%

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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C=150$ mA, $I_B=15$ mA		0.40	V
		$I_C=500$ mA, $I_B=50$ mA		0.75	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	$I_C=150$ mA, $I_B=15$ mA	0.75	0.95	V
		$I_C=500$ mA, $I_B=50$ mA		1.30	V

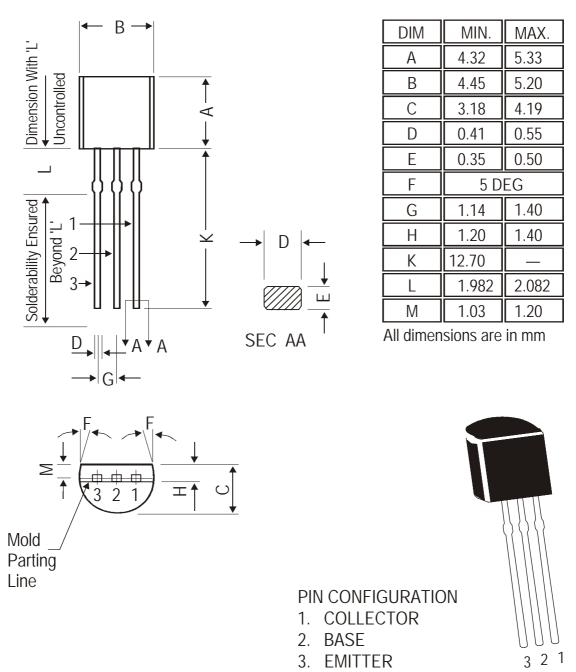
SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	2N4402 2N4403		UNITS
Transition Frequency	f⊤	I _C =20mA, V _{CE} =10V, f=100MHz	mA, V _{CE} =10V, f=100MHz >150 >200		
Collector Base Capacitance	C_{cb}	V _{CB} =10V, I _E =0, f=140KHz	< 8	3.5	pF
Emitter Base Capacitance	C _{eb}	V_{EB} =0.5V, I_{C} =0, f=140KHz	<3	30	pF
Input Inpedence	h _{ie}	I _C =1mA, V _{CE} =10V, f=1KHz	750 - 7.5K	1.5K - 15K	Ω
Voltage Feedback Ratio	h _{re}	I _C =1mA, V _{CE} =10V, f=1KHz	0.1 -	- 8.0	x10 ⁻⁴
Small Signal Current Gain	h _{fe}	I _C =1mA, V _{CE} =10V, f=1KHz	30 - 250	60 - 500	
Out put Admittance	h _{oe}	$I_C=1$ mA, $V_{CE}=10$ V, $f=1$ KHz	1.0 - 100		μmhos
SWITCHING Time					
Delay time	t _d	$V_{CC}=30, V_{EB}=2V$	<	15	ns
Rise time	t _r	$I_C=150$ mA, $I_{B1}=15$ mA	< 20		ns
	•				
Storage time	t _s	V_{CC} =30V, I_{C} =150mA	< 225		ns
Fall time	t _f	I _{B1} =1 _{B2} =15mA	< 30		ns

^{*}Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2%

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TO-92 Plastic Package



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

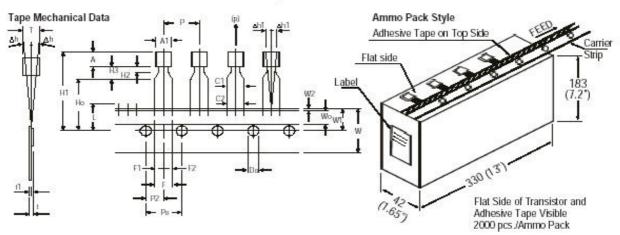
Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size Oty		Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Plastic Package For Lead Free Parts, Device

For Lead Free Parts, Device Part # will be Prefixed with





All dimensions are in mm

		SPECIFICATION				
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.45		5.20		NOTES
BODY HEIGHT	Α	4.32		5.33		Maximum alignment deviation between
BODY THICKNESS	T	3.18		4.19		leads will not to be greater than 0.2mm.
PITCH OF COMPONENT	P		12.7		± 1.0	Maximum non-cumulative variation
*1FEED HOLE PITCH	Po		12.7		± 0.3	between tape feed holes shall not
*2 FEED HOLE CENTRE TO	140,50		11000000			exceed 1 mm in 20 pitches.
COMPONENT CENTRE	P2		6.35		± 0.4	3. Holddown tape will not exceed beyond
DISTANCE BETWEEN OUTER LEADS	F:		5.08		+ 0.6	the edge(s) of carrier tape and there shall be no exposure of adhesive.
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		4. There will be no more than three (3)
*4 COMPONENT ALIGNMENT FRONT VIEW			0	1.3		consecutive missing components in a
TAPE WIDTH	W		18	66686	± 0.5	tape.
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	5. A tape trailer, having at least three feed
HOLE POSITION	W1		9		+ 0.7	holes are provided after the last component in a tape.
HOLD-DOWN TAPE POSITION	W2	0.0		0.7		Splices should not interfere with the
LEAD WIRE CLINCH HEIGHT	Ho	7/20/2009	16	11000000	± 0.5	sprocket feed holes.
COMPONENT HEIGHT	H1		1000	24.0		
LENGTH OF SNIPPED LEADS	L L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	REMARKS
*5 TOTAL TAPE THICKNESS	t			1.2		
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70		*1 Cumulative pitch error 1.0 mm/20 pitch
STAND OFF	H2	0.45		1.45	- 0.1	*2 To be measured at bottom of clinch
CLINCH HEIGHT	HZ H3	0.45		3.0		*3 At top of body
LEAD PARALLELISM	C1 - C2			0.22		*4 At top of body
PULL - OUT FORCE	(p)	6N		0.22		*5 t1 0.3 = 0.6 mm

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Customer Notes 2N4402 / 2N4403

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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